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## INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

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50T5690.01

Application Number

10/800,348

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Applicant(s)

Tenko Yamashita

Filing Date

Filed Herewith

Group Art Unit

~~Unassigned~~ 2814

## U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

## FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

TD	1	Momose, H.S. et al., "1.5-nm Gate Oxide CMOS on (110) Surface-Oriented Si Substrate," IEEE Transactions On Electron Devices, Vol. 50, No. 4, April 2003, pp. 1001-1008.

EXAMINER

Zhuoan

DATE CONSIDERED

04/29/05

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.




08/10/04

## ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

Title of Invention	SILICON-ON INSULATOR (SOI) SUBSTRATE HAVING DUAL SURFACE CRYSTALLOGRAPHIC ORIENTATIONS AND METHOD OF FORMING SAME																																																																																										
<p>Application Number: 10/800348 </p> <p>Confirmation Number: 9885</p> <p>First Named Applicant: Tenko Yamashita</p> <p>Attorney Docket Number: 50T5690.01</p> <p>Art Unit: 2814</p> <p>Search string: ( 5841170 or 6391692 or 6476445 or 6503813 or 6559035 or 6566712 or 6593173 or 6627505 or 6649455 ).pn.</p> <p>US Patent Documents</p> <p>Note: Applicant is not required to submit a paper copy of cited US Patent Documents</p> <table border="1"><thead><tr><th>init</th><th>Cite.No.</th><th>Patent No.</th><th>Date</th><th>Patentee</th><th>Kind</th><th>Class</th><th>Subclass</th></tr></thead><tbody><tr><td>TD</td><td>1</td><td>5841170</td><td>1998-11-24</td><td>Adan et al.</td><td></td><td>257</td><td>345</td></tr><tr><td>TD</td><td>2</td><td>6391692</td><td>2002-05-21</td><td>Nakamura</td><td>B1</td><td>438</td><td>151</td></tr><tr><td>TD</td><td>3</td><td>6476445</td><td>2002-11-05</td><td>Brown et al.</td><td>B1</td><td>257</td><td>347</td></tr><tr><td>TD</td><td>4</td><td>6503813</td><td>2003-01-07</td><td>Koburger, III</td><td>B1</td><td>438</td><td>424</td></tr><tr><td>TD</td><td>5</td><td>6559035</td><td>2003-05-06</td><td>Villa et al.</td><td>B2</td><td>438</td><td>481</td></tr><tr><td>TD</td><td>6</td><td>6566712</td><td>2003-05-20</td><td>Hayashi et al.</td><td>B2</td><td>257</td><td>347</td></tr><tr><td>TD</td><td>7</td><td>6593173</td><td>2003-07-15</td><td>Anc et al.</td><td>B1</td><td>438</td><td>149</td></tr><tr><td>TD</td><td>8</td><td>6627505</td><td>2003-09-30</td><td>Adan</td><td>B2</td><td>438</td><td>311</td></tr><tr><td>TD</td><td>9</td><td>6649455</td><td>2003-11-18</td><td>Murakami</td><td>B2</td><td>438</td><td>149</td></tr></tbody></table> <p>Signature</p> <table border="1"><thead><tr><th>Examiner Name</th><th>Date</th></tr></thead><tbody><tr><td><i>S. Ivan</i></td><td><i>4/27/05</i></td></tr></tbody></table>								init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass	TD	1	5841170	1998-11-24	Adan et al.		257	345	TD	2	6391692	2002-05-21	Nakamura	B1	438	151	TD	3	6476445	2002-11-05	Brown et al.	B1	257	347	TD	4	6503813	2003-01-07	Koburger, III	B1	438	424	TD	5	6559035	2003-05-06	Villa et al.	B2	438	481	TD	6	6566712	2003-05-20	Hayashi et al.	B2	257	347	TD	7	6593173	2003-07-15	Anc et al.	B1	438	149	TD	8	6627505	2003-09-30	Adan	B2	438	311	TD	9	6649455	2003-11-18	Murakami	B2	438	149	Examiner Name	Date	<i>S. Ivan</i>	<i>4/27/05</i>
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